

Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The proprietary barrier technology allows for reliable operation up to 175°C junction temperature. Typical application are in switching Mode Power Supplies such as adaptors, DC/DC converters, freewheeling and polarity protection diodes.

Features

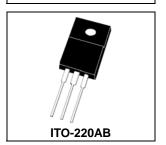
- *Low Forward Voltage.
- *Low Switching noise.
- *High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- *Low Power Loss & High efficiency.
- *175℃ Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory

Flammability Classification 94V-O



SCHOTTKY BARRIER RECTIFIERS

10 AMPERES 120 VOLTS



* In compliance with EU RoHs 2002/95/EC directives

MAXIMUM RATINGS

Characteristic	Symbol	MBRF10120C	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	120	V
RMS Reverse Voltage	$V_{R(RMS)}$	84	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R), T_C =125 $^{\circ}$ C	I _{F(AV)}	5 10	А
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	20	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	125	Α
Operating and Storage Junction Temperature Range	T_J , T_{stg}	-65 to +175	$^{\circ}$

THERMAL RESISTANCES

Typical Thermal Resistance junction to case	R _{θjc}	3.4	°C/w	

ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	MBRF10120C	Unit
Maximum Instantaneous Forward Voltage (per diode)			
(I _F =5 Amp T _C = 25°C)	V_{F}	0.85	V
(I _F =5 Amp T _C = 125°C)		0.76	
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R	0.01 10	mA

MBRF10120C



